

## Solution to Exercise 3.2-1 "Crystal Identity"

Illustration

The jump rate of a vacancy is identical to that of an atom next to the vacancy. It was given by

$$v = v_0 \cdot \exp - \frac{G_m}{kT} \approx v_0 \cdot \exp - \frac{H_m}{kT}$$

The time  $t_a$  needed so that all the atoms with a vacancy next to them will make *one* jump thus is

$$t_a = \frac{1}{v} = \frac{1}{v_0} \cdot \exp \frac{H_m}{kT}$$

After *that* time  $t_a$ , the fraction of all atoms that had a vacancy a a neighbor, has made *one* jump.

- If you now wait another  $t_a$ , a *second* set of atoms can now make a jump. This second set may include atoms from the first set which simply jump back to their old position, but we ignore this effect for a rough estimate.
- If all atoms of the crystal are supposed to make one jump, you have to wait for a time  $t_c$  that is a defined multiple of  $t_a$ . It is simply

$$t_c = m \cdot t_a = \frac{t_a}{c_v}$$

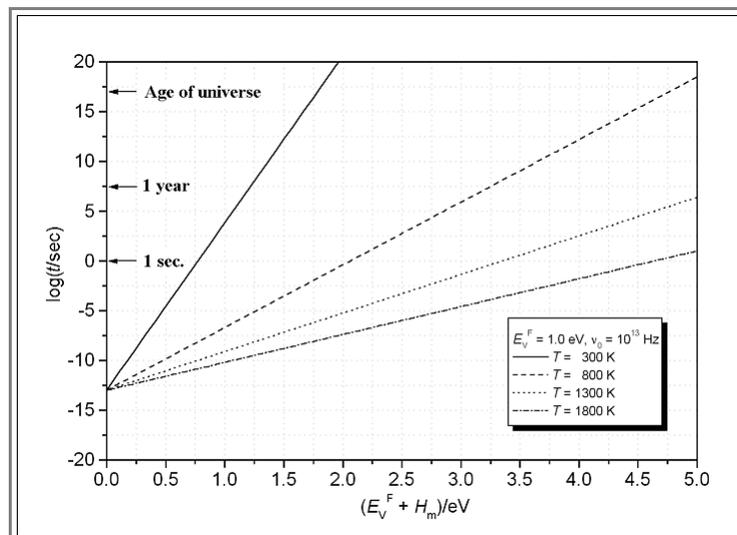
Because the multiplier  $m$  is of course the inverse of the vacancy concentration  $c_v = \exp - (H_f)/kT$

$t_c$  is the quantity we we are looking for, it is

$$t_c = \frac{1}{v_0} \cdot \exp \frac{H_m}{kT} \cdot \exp \frac{H_f}{kT} = \frac{1}{v_0} \cdot \exp \frac{H_m + H_f}{kT} = \frac{1}{v_0} \cdot \exp \frac{H_{SD}}{kT}$$

With  $H_{SD}$  = enthalpy of self diffusion.

We may replace  $1/v_0$  by  $1/v_0 = g \cdot a^2 / D_{SD}$  and use the diffusion coefficient for self-diffusion to obtain values for specific materials, but lets just look at what we get in a very simple approximation with  $v_0 = 10^{13}$  Hz



Shown is  $t_c$  on a (rather far-reaching) **log** scale versus  $H_m + H_f = H_{SD}$ , i.e. the self-diffusion enthalpy  $H_{SD}$ , with the temperature as a parameter.

For  $H_m + H_f = 0$ ,  $t_c$  is  $10^{-13}$  s - as it should be.

● For sensible values. e.g.  $H_{SD} = 2 \text{ eV}$ , you must be very patient at room temperature, but at  $800 \text{ }^\circ\text{C}$ , your crystal has a different identity after **1 second!** Take **Si**, with  $H_{SD} \approx 5 \text{ eV}$  and a melting point of roughly **1700 K**, and again no atom will be where it was after a rather short time.

▮ Using better values for  $\nu_0$  from the self-diffusion coefficient as stated above, just shifts the whole set of curves a "little bit" on the  $t$  - axis and thus  $t_c$  by the same (logarithmic) amount